## **General Purpose Transistor**

## **PNP Silicon**

## **PZT3906T1G**

#### **Features**

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CEO</sub>	-40	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	-40	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Collector Current - Continuous	Ic	-200	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation (Note 1) $T_A = 25^{\circ}C$	P <sub>D</sub>	1.5 12	W mW/°C
Thermal Resistance Junction-to-Ambient (Note 1)	$R_{\theta JA}$	83.3	°C/W
Thermal Resistance Junction-to-Lead #4	$R_{\theta JA}$	35	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

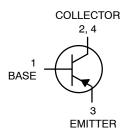
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-4 with 1 oz and 713 mm<sup>2</sup> of copper area.



## ON Semiconductor®

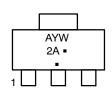
### www.onsemi.com



## **MARKING DIAGRAM**



SOT-223 CASE 318E



2A = Specific Device Code = Assembly Location Α

= Year W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

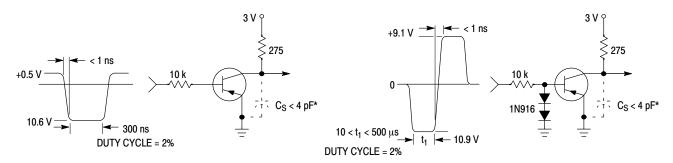
Device	Package	Shipping <sup>†</sup>
PZT3906T1G	SOT-223 (Pb-Free)	1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Charac	eteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS (Note 2)					
Collector – Emitter Breakdown Voltage (Note $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	2)	V <sub>(BR)CEO</sub>	-40	_	Vdc
Collector – Base Breakdown Voltage $(I_C = -10 \mu Adc, I_E = 0)$		V <sub>(BR)CBO</sub>	-40	-	
Emitter – Base Breakdown Voltage ( $I_E = -10 \mu Adc, I_C = 0$ )		V <sub>(BR)EBO</sub>	-5.0	-	
Base Cutoff Current (V <sub>CE</sub> = -30 Vdc, V <sub>EB</sub> = -3.0 Vdc)		I <sub>BL</sub>	_	-50	nAdc
Collector Cutoff Current (V <sub>CE</sub> = -30 Vdc, V <sub>EB</sub> = -3.0 Vdc)		I <sub>CEX</sub>	_	-50	_
ON CHARACTERISTICS (Note 2)					
$\begin{array}{l} \text{DC Current Gain} \\ (I_C = -0.1 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \\ (I_C = -1.0 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \\ (I_C = -10 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \\ (I_C = -50 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \\ (I_C = -100 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc}) \end{array}$		H <sub>FE</sub>	60 80 100 60 30	- 300 - -	-
Collector – Emitter Saturation Voltage ( $I_C = -10$ mAdc, $I_B = -1.0$ mAdc) ( $I_C = -50$ mAdc, $I_B = -5.0$ mAdc)		V <sub>CE(sat)</sub>	-	-0.25 -0.4	Vdc
Base – Emitter Saturation Voltage ( $I_C = -10$ mAdc, $I_B = -1.0$ mAdc) ( $I_C = -50$ mAdc, $I_B = -5.0$ mAdc)		V <sub>BE(sat)</sub>	-0.65 -	-0.85 -0.95	
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (I <sub>C</sub> = –10 mAdc, V <sub>CE</sub> = –20 Vdc, f = 100 M	ЛНz)	f <sub>T</sub>	250	_	MHz
Output Capacitance ( $V_{CB} = -5.0 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )		C <sub>obo</sub>	1	4.5	pF
Input Capacitance ( $V_{EB} = -0.5 \text{ Vdc}$ , $I_{C} = 0$ , $f = 1.0 \text{ MHz}$ )		C <sub>ibo</sub>	ı	10	
Input Impedance (I <sub>C</sub> = $-1.0$ mAdc, V <sub>CE</sub> = $-10$ Vdc, f = $1.0$ k	Hz)	h <sub>ie</sub>	2.0	12	kΩ
Voltage Feedback Ratio ( $I_C = -1.0 \text{ mAdc}$ , $V_{CE} = -10 \text{ Vdc}$ , $f = 1.0 \text{ kg}$	Hz)	h <sub>re</sub>	0.1	10	X 10 <sup>-4</sup>
$Small-Signal\ Current\ Gain \\ (I_C=-1.0\ mAdc,\ V_{CE}=-10\ Vdc,\ f=1.0\ kc)$	Hz)	h <sub>fe</sub>	100	400	_
Output Admittance ( $I_C = -1.0 \text{ mAdc}$ , $V_{CE} = -10 \text{ Vdc}$ , $f = 1.0 \text{ k}$	Hz)	h <sub>oe</sub>	3.0	60	μmhos
Noise Figure (I <sub>C</sub> = -100 $\mu$ Adc, V <sub>CE</sub> = -5.0 Vdc, R <sub>S</sub> = 1.0 k $\Omega$ , f = 1.0 kHz)		NF	_	4.0	dB
SWITCHING CHARACTERISTICS					
Delay Time	$(V_{CC} = -3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc}, I_{C} = -10 \text{ mAdc}, I_{B1} = -1.0 \text{ mAdc})$	t <sub>d</sub>	-	35	
Rise Time		t <sub>r</sub>	-	35	ns
Storage Time	$(V_{CC} = -3.0 \text{ Vdc}, I_C = -10 \text{ mAdc}, I_{B1} = I_{B2} = -1.0 \text{ mAdc})$	t <sub>s</sub>	-	225	113
Fall Time		t <sub>f</sub>	-	75	

<sup>2.</sup> Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.



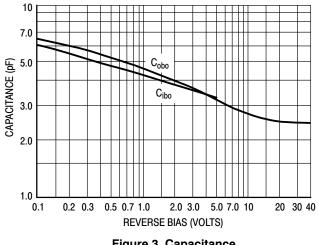
\* Total shunt capacitance of test jig and connectors

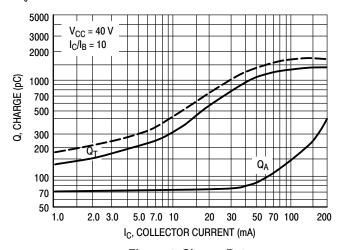
Figure 1. Delay and Rise Time Equivalent Test Circuit

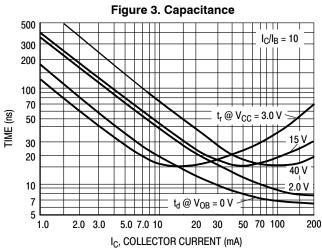
Figure 2. Storage and Fall Time Equivalent Test Circuit

### TYPICAL TRANSIENT CHARACTERISTICS

T<sub>J</sub> = 25°C
T<sub>J</sub> = 125°C







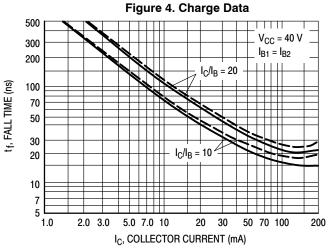


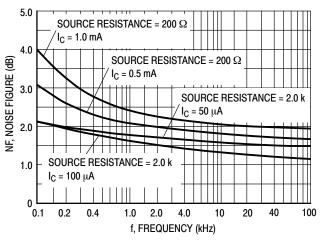
Figure 5. Turn - On Time

Figure 6. Fall Time

# TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$ 

NF, NOISE FIGURE (dB)



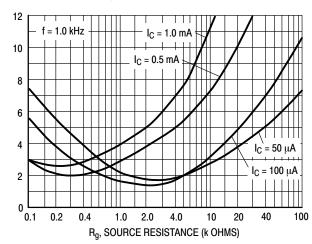


Figure 7.

Figure 8.

## **h PARAMETERS**

( $V_{CE}$  = -10 Vdc, f = 1.0 kHz,  $T_A$  = 25°C)

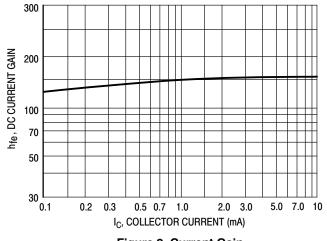
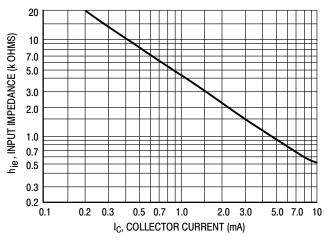


Figure 9. Current Gain

Figure 10. Output Admittance



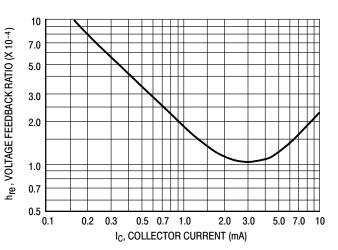


Figure 11. Input Impedance

Figure 12. Voltage Feedback Ratio

## TYPICAL STATIC CHARACTERISTICS

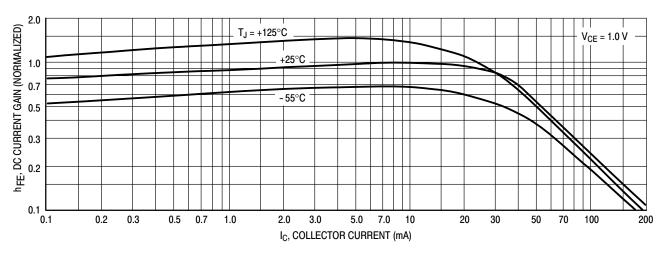


Figure 13. DC Current Gain

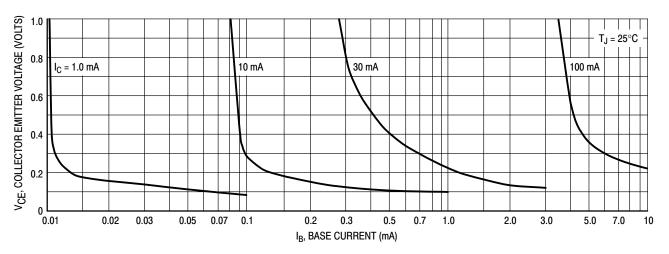


Figure 14. Collector Saturation Region

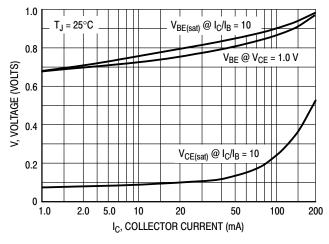
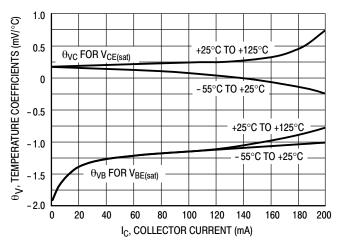


Figure 15. "ON" Voltages



**Figure 16. Temperature Coefficients** 

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